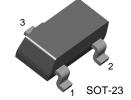


FJV3105R

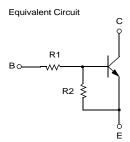
Switching Application (Bias Resistor Built In)

- Switching circuit, Inverter, Interface circuit, Driver Circuit
- Built in bias Resistor (R₁=4.7K Ω , R₂=10K Ω)
- Complement to FJV4105R



1. Base 2. Emitter 3. Collector





NPN Epitaxial Silicon Transistor

Absolute Maximum Ratings T_a =25°C unless otherwise noted

Symbol	Parameter	Value	Units
V_{CBO}	Collector-Base Voltage	50	V
V _{CEO}	Collector-Emitter Voltage 50		V
V _{EBO}	Emitter-Base Voltage	10	V
I _C	Collector Current	100	mA
P _C	Collector Power Dissipation	200	mW
T _J	Junction Temperature	150	°C
T _{STG}	Storage Temperature	-55 ~ 150	°C

Electrical Characteristics T_a =25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV _{CBO}	Collector-Base Breakdown Voltage	$I_{C}=10\mu A, I_{E}=0$	50			V
BV _{CEO}	Collector-Emitter Breakdown Voltage	I _C =100μA, I _B =0	50			V
I _{CBO}	Collector Cut-off Current	V_{CB} =40V, I_{E} =0			0.1	μΑ
h _{FE}	DC Current Gain	V _{CE} =5V, I _C =5mA	30			
V _{CE} (sat)	Collector-Emitter Saturation Voltage	I _C =10mA, I _B =0.5mA			0.3	V
C _{ob}	Output Capacitance	V _{CE} =10V, I _C =5mA f=1MHz		3.7		pF
f _T	Current Gain Bandwidth Product	V _{CE} =10V, I _C =5mA		250		MHz
V _I (off)	Input Off Voltage	V _{CE} =5V, I _C =100μA	0.3			V
V _I (on)	Input On Voltage	V_{CE} =0.3V, I_{C} =20mA			2.5	V
R ₁	Input Resistor		3.2	4.7	6.2	ΚΩ
R ₁ /R ₂	Resistor Ratio		0.42	0.47	0.52	

Typical Characteristics

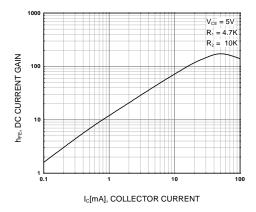


Figure 1. DC current Gain

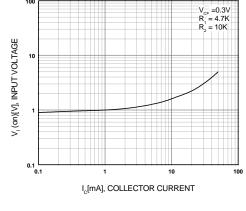


Figure 2. Input On Voltage

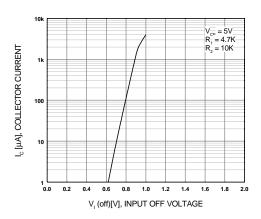


Figure 3. Input Off Voltage

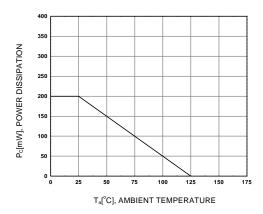
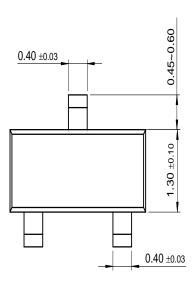
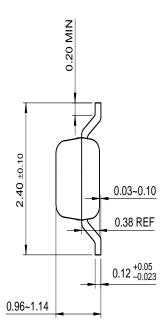


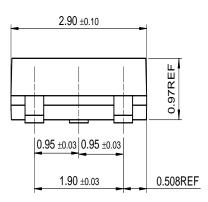
Figure 4. Power Derating

Package Dimensions

SOT-23







Dimensions in Millimeters

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CoolFET™	FASTr™	MicroFET™	PowerTrench®	SuperSOT™-6
CROSSVOLT™	FRFET™	MicroPak™	QFET™	SuperSOT™-8
DOME™	GlobalOptoisolator™	MICROWIRE™	QS™	SyncFET™
EcoSPARK™	GTO™	MSX™	QT Optoelectronics™	TinyLogic™
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EnSigna™	I ² C™	OCX TM	RapidConfigure™	UHC™
Across the board	. Around the world.™	OCXPro™	RapidConnect™	UltraFET [®]
The Power Franchise™		OPTOLOGIC®	SILENT SWITCHER®	VCX™
Programmable Ad	ctive Droop™	OPTOPLANAR™	SMART START™	

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